

Silicon PNP Power Transistors

2SB776

DESCRIPTION

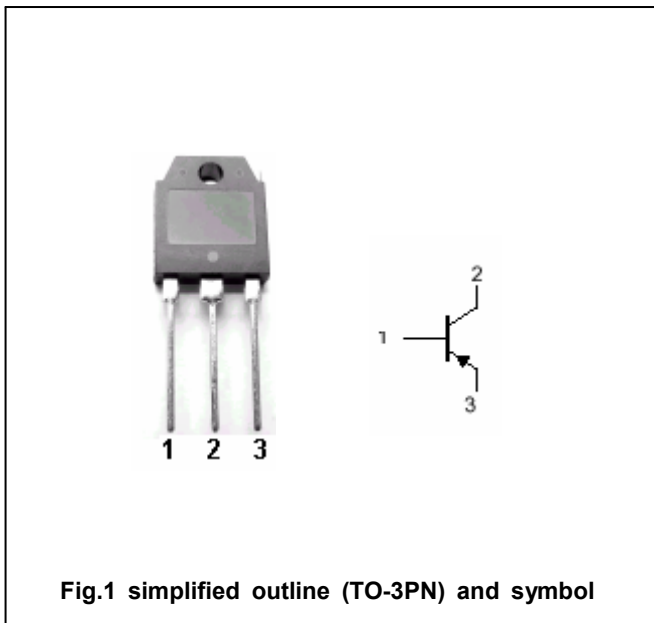
- With TO-3PN package
- Complement to type 2SD896
- Wide area of safe operation

APPLICATIONS

- 100V/7A, AF 40W output applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter

Absolute maximum ratings($T_c=25^\circ\text{C}$)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-base voltage	Open emitter	-120	V
V_{CEO}	Collector-emitter voltage	Open base	-100	V
V_{EBO}	Emitter-base voltage	Open collector	-6	V
I_C	Collector current (DC)		-7	A
I_{CM}	Collector current-peak		-11	A
P_C	Collector power dissipation	$T_c=25^\circ\text{C}$	70	W
T_j	Junction temperature		150	$^\circ\text{C}$
T_{stg}	Storage temperature		-55~150	$^\circ\text{C}$

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CHARACTERISTICS

T_j=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =-50mA ; R _{BE} =∞	-100			V
V _{(BR)CBO}	Collector-base breakdown voltage	I _C =-5mA ; I _E =0	-120			V
V _{(BR)EBO}	Emitter-base breakdown voltage	I _E =-5mA ; I _C =0	-6			V
V _{CEsat}	Collector-emitter saturation voltage	I _C =-4A ; I _B =-0.4A		-0.9	-2.0	V
V _{BE}	Base-emitter on voltage	I _C =-1A ; V _{CE} =-5V			-1.5	V
I _{CBO}	Collector cut-off current	V _{CB} =-80V I _E =0			-0.1	mA
I _{EBO}	Emitter cut-off current	V _{EB} =-4V ; I _C =0			-0.1	mA
h _{FE-1}	DC current gain	I _C =-1A ; V _{CE} =-5V	60		200	
h _{FE-2}	DC current gain	I _C =-4A ; V _{CE} =-5V	20			
f _T	Transition frequency	I _C =-1A ; V _{CE} =-5V		15		MHz
C _{OB}	Collector output capacitance	f=1MHz ; V _{CB} =10V		200		pF

Switching times

t _{on}	Turn-on time	I _C =-1.0A ; I _{B1} =-I _{B2} =-0.1A R _L =20Ω ; V _{CC} =20V		0.2		μs
t _{stg}	Storage time			1.2		μs
t _f	Fall time			0.3		μs

◆ h_{FE-1} Classifications

D	E
60-120	100-200

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PACKAGE OUTLINE

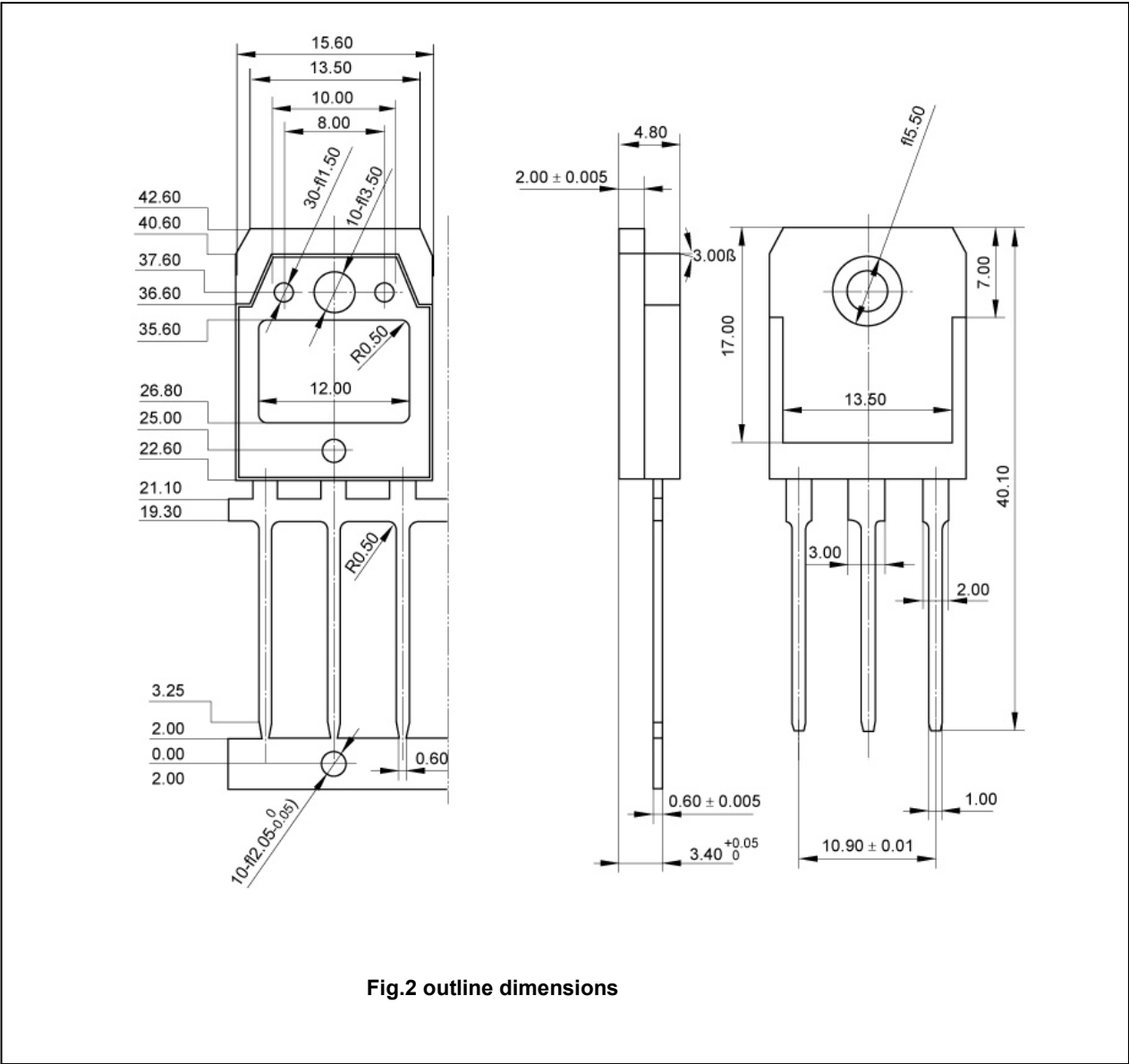


Fig.2 outline dimensions

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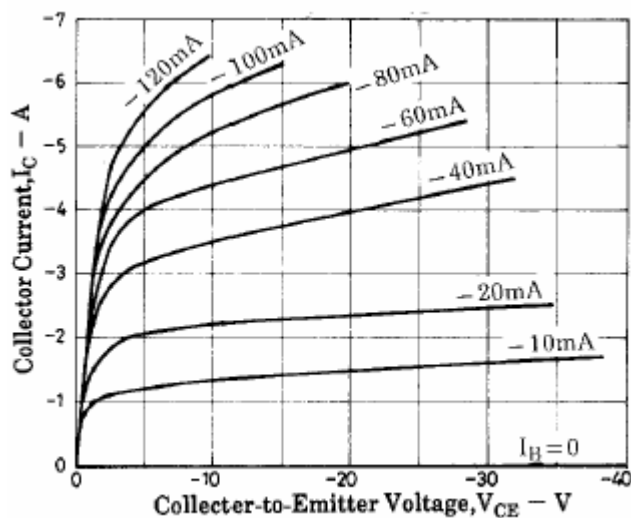


Fig.3 Static Characteristic

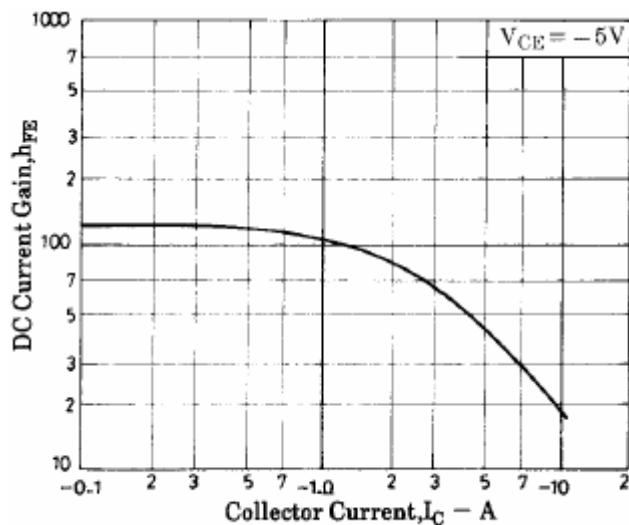


Fig.4 DC current Gain

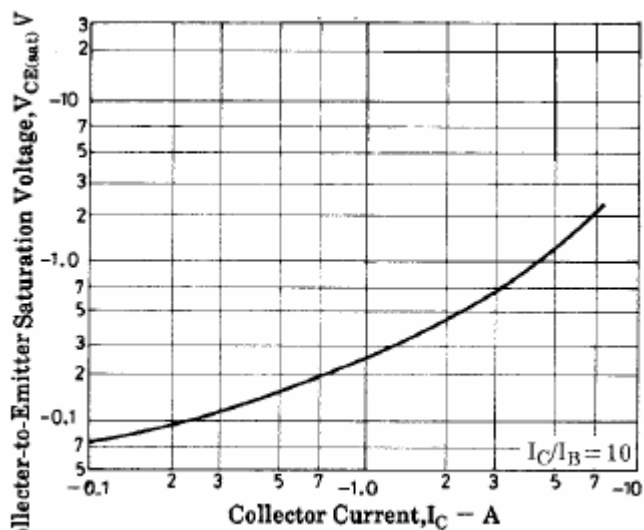


Fig.5 Collector-Emitter Saturation Voltage

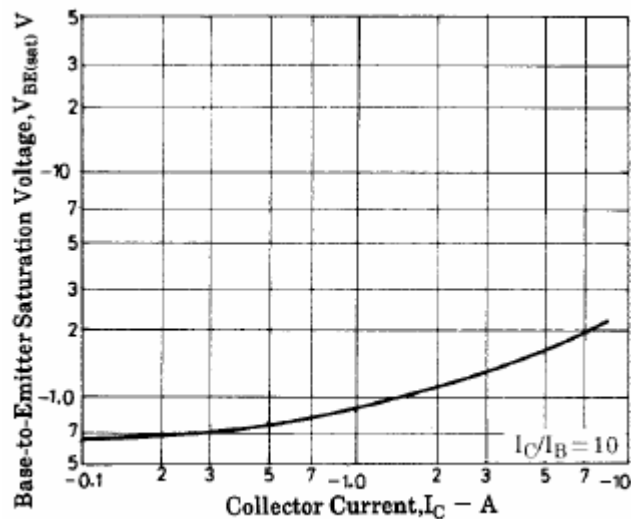


Fig.6 Base-Emitter Saturation Voltage

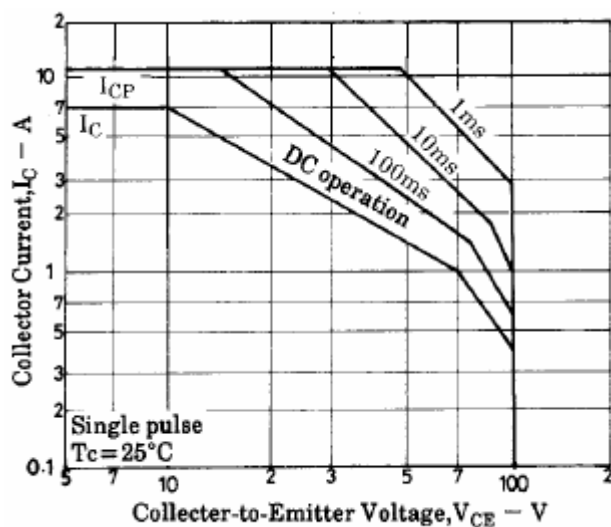


Fig.7 Safe Operating Area